TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

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BLACK AND WHITE TV VIDEO OUTPUT APPLICATIONS
HIGH VOLTAGE SWITCHING APPLICATIONS
DRIVER STAGE AUDIO AMPLIFIER APPLICATIONS

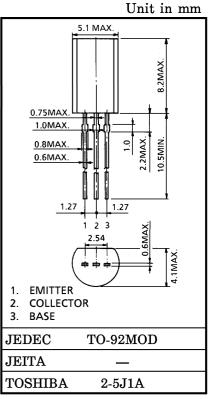
• High Breakdown Voltage : V_{CEO}=150V (Min.)

• Low Output Capacitance : Cob=5.0pF (Max.)

• High Transition Frequency: fr=120MHz (Typ.)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	200	V
Collector-Emitter Voltage	v_{CEO}	150	V
Emitter-Base Voltage	$V_{ m EBO}$	5	V
Collector Current	$I_{\mathbf{C}}$	50	mA
Base Current	$I_{\mathbf{B}}$	20	mA
Collector Power Dissipation	PC	800	mW
Junction Temperature	$T_{ m j}$	150	°C
Storage Temperature Range	${ m T_{stg}}$	-55~150	°C



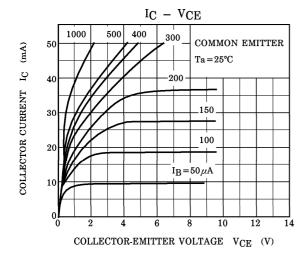
Weight: 0.36g (Typ.)

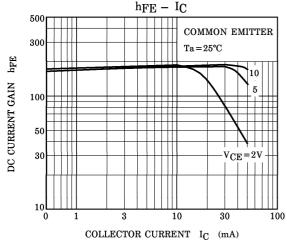
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

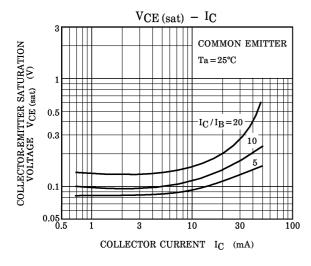
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	$V_{CB} = 200V, I_{E} = 0$	_		0.1	μ A
Emitter Cut-off Current	I _{EBO}	$V_{EB}=5V, I_{C}=0$		l	0.1	μ A
DC Current Gain	h _{FE} (Note)	$V_{\text{CE}} = 5V$, $I_{\text{C}} = 10\text{mA}$	70	1	240	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$I_{\rm C}$ =10mA, $I_{\rm B}$ =1mA	_	_	0.5	V
Base-Emitter Saturation Voltage	V _{BE} (sat)	$I_C=10$ mA, $I_B=1$ mA	_	_	1	V
Transition Frequency	${ m f_T}$	V_{CE} =30V, I_{C} =10mA	_	120	_	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$	_	3.5	5	pF

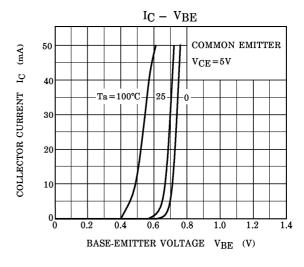
(Note) : h_{FE} Classification $O:70\sim140$, $Y:120\sim240$

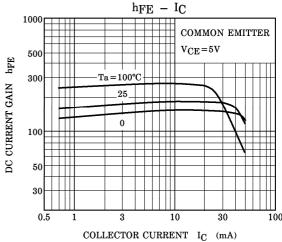
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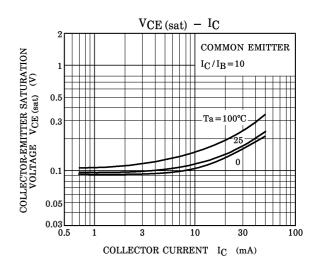




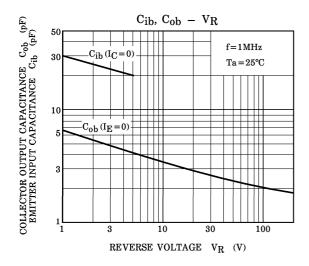


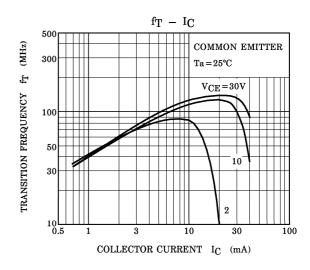


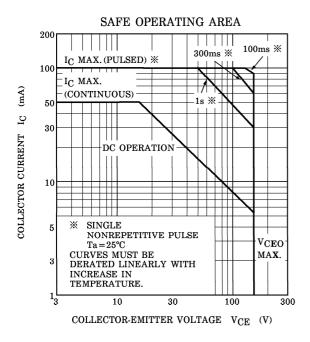


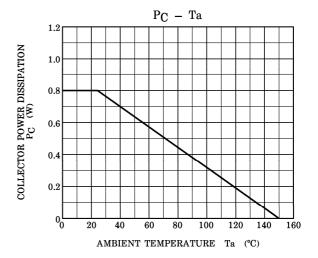


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